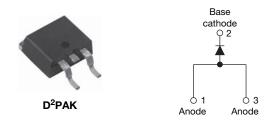


VS-20ETS08SPbF, VS-20ETS12SPbF Series

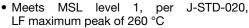
Vishay Semiconductors

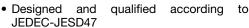
High Voltage Surface Mount Input Rectifier Diode, 20 A



PRODUCT SUMMARY					
Package	TO-263AB (D ² PAK)				
$I_{F(AV)}$	20 A				
V_{R}	800 V, 1200 V				
V _F at I _F	1.1 V				
I _{FSM}	300 A				
T _j max.	150 °C				
Diode variation	Single die				

FEATURES











ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- · Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-20ETS...SPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter T _A = 55 °C, T _J = 125 °C common heatsink of 1 °C/W	16.3	21	А			

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Sinusoidal waveform	20	А				
V _{RRM}		800/1200	V				
I _{FSM}		300	A				
V _F	20 A, T _J = 25 °C	1.1	V				
TJ		- 40 to 150	°C				

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
VS-20ETS08SPbF	800	900	1			
VS-20ETS12SPbF	1200	1300	l			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	T _C = 105 °C, 180° conduction half sine wave	20			
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	250	Α		
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s		
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-5		
Maximum I ² √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s		



VS-20ETS08SPbF, VS-20ETS12SPbF Series

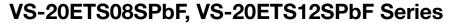
Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER SYMBOL TEST CONDITIONS VALUES UN						
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C	20 A, T _J = 25 °C			
Forward slope resistance	r _t	T 450.00		10.4	mΩ	
Threshold voltage	V _{F(TO)}	1J = 150 C	T _J = 150 °C			
Maximum rayarea laakaga ayrrant	1	T _J = 25 °C	V Patod V	0.1	mΛ	
Maximum reverse leakage current	IRM	T _J = 150 °C	V _R = Rated V _{RRM}	1.0	mA	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperatu	ure range	T_J , T_{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case		R_{thJC}	DC operation	1.3		
Maximum thermal resistance, junction to ambient		R _{thJA} ⁽¹⁾	For D ² PAK version	62	°C/W	
Typical thermal resistance, case to heatsink	·		Mounting surface, smooth and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
	inimum			6.0 (5.0)	kgf · cm	
Mounting torque ————————————————————————————————————	aximum			12 (10)	(lbf \cdot in)	
Mand the side than			Case style D ² PAK (SMD-220)	20ETS08S		
Marking device			Case style D-PAR (SIVID-220)	20ETS12S		

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994





www.vishay.com

Vishay Semiconductors

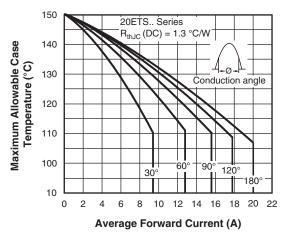


Fig. 1 - Current Rating Characteristics

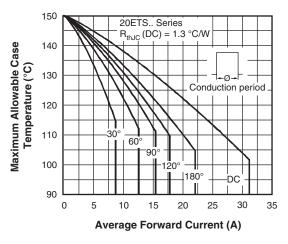


Fig. 2 - Current Rating Characteristics

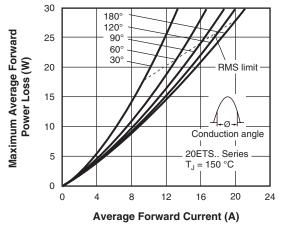


Fig. 3 - Forward Power Loss Characteristics

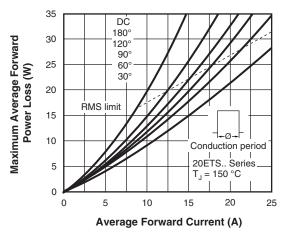
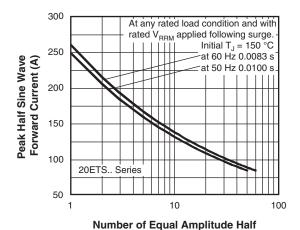


Fig. 4 - Forward Power Loss Characteristics



Cycle Current Pulse (N)
Fig. 5 - Maximum Non-Repetitive Surge Current

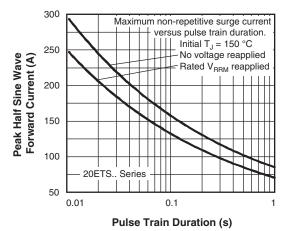


Fig. 6 - Maximum Non-Repetitive Surge Current

Vishay Semiconductors

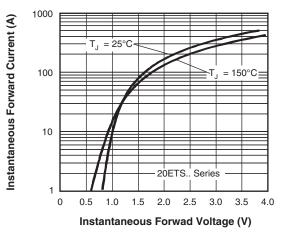


Fig. 7 - Forward Voltage Drop Characteristics

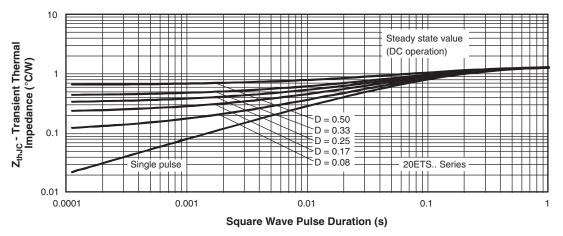


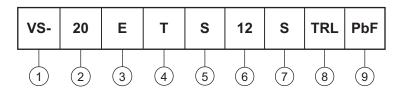
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

VS-20ETS08SPbF, VS-20ETS12SPbF Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (20 = 20 A)

Circuit configuration

E = Single diode

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = Standard recovery rectifier

- Voltage code x 100 = V_{RRM} - 08 = 800 V 12 = 1200 V

7 - S = TO-220 D²PAK (SMD-220) version

8 - • None = Tube

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

9 - PbF = Lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-20ETS08SPbF	50	1000	Antistatic plastic tube				
VS-20ETS08STRRPbF	800	800	13" diameter reel				
VS-20ETS08STRLPbF	800	800	13" diameter reel				
VS-20ETS12SPbF	50	1000	Antistatic plastic tube				
VS-20ETS12STRRPbF	800	800	13" diameter reel				
VS-20ETS12STRLPbF	800	800	13" diameter reel				

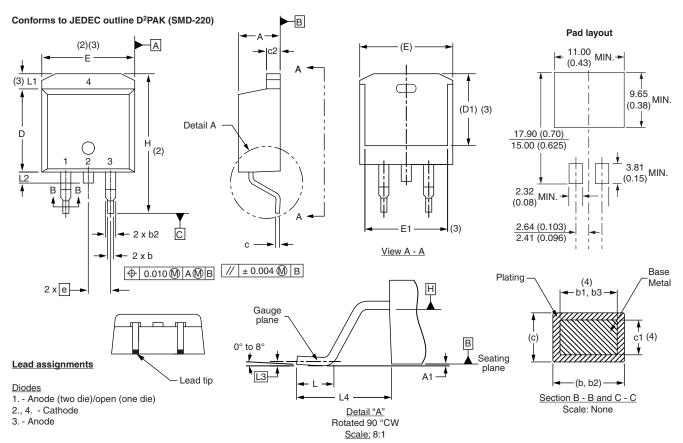
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95046</u>				
Part marking information	www.vishay.com/doc?95054			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?95409			



Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INCHES		NOTES
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	2.54 BSC		0.100 BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	1	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB



Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000